



DMN2013UFX-7 Information



For Reference Only

Part Number DMN2013UFX-7 **Manufacturer** Diodes Incorporated

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

Description MOSFET 2N-CH 20V 10A 6-DFN

Package 6-VFDFN Exposed Pad

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









DMN2013UFX-7 Specifications

Manufacturer Part Number	DMN2013UFX-7
Manufacturer	Diodes Incorporated
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	6-VFDFN Exposed Pad
Series	-
FET Type	2 N-Channel (Dual) Common Drain
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	20V
Current - Continuous Drain (Id) @ 25°C	10A
Rds On (Max) @ Id, Vgs	11.5 mOhm @ 8.5A, 4.5V
Vgs(th) (Max) @ Id	1.1V @ 250μA
Gate Charge (Qg) (Max) @ Vgs	57.4nC @ 8V
Input Capacitance (Ciss) (Max) @ Vds	2607pF @ 10V
Power - Max	780mW
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	6-VFDFN Exposed Pad
Supplier Device Package	W-DFN5020-6
	Report errors?

DMN2013UFX-7 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

DMN2013UFX-7 Payment Methods



















DMN2013UFX-7 Shipping Methods













If you have any question about DMN2013UFX-7, please do not hesitate to contact us!

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